



**IN THE UNITED STATES PATENT AND TRADEMARK OFFICE**

In re Application of: Bernard Q. Li

Serial No.: 10/623,351

Examiner: Unknown

Filed: July 18, 2003

Group Art Unit: Unknown

For: EDGE BEAD METHOD AND APPARATUS

Docket No.: H0004337 (1139.1132101)

**TRANSMITTAL SHEET**

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By

Mark R. Schroeder

We are transmitting herewith the attached:

- ☒ Information Disclosure Statement.
- ☒ Form 1449 with two-hundred forty-eight (248) references.
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By:

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P A T E N T

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**INFORMATION DISCLOSURE STATEMENT (37 C.F.R. §1.97)**

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By

Mark R. Schroeder

Dear Sirs:

Pursuant to the obligations of candor and good faith imposed by 37 C.F.R. 1.56, the documents listed on the attached PTO-1449 are hereby disclosed.

No representation is intended to be made hereby that any of the cited references establishes, by itself or in combination with other information, a prima facie case of unpatentability of any claim of the present case.

Respectfully submitted,

Dated: 10-10-03

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FORM PTO-1449


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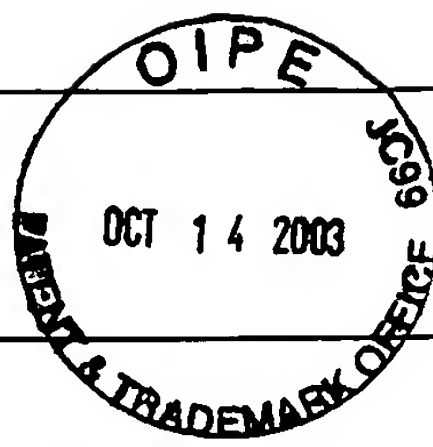
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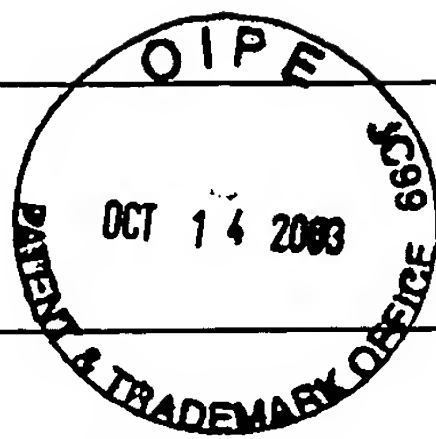
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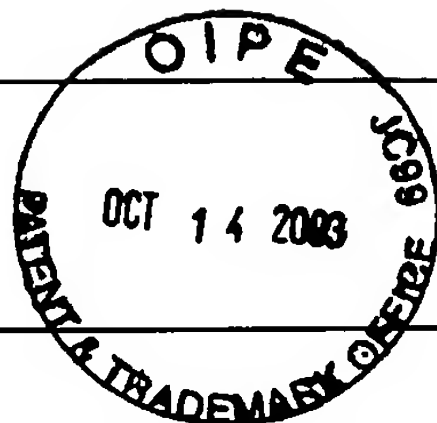
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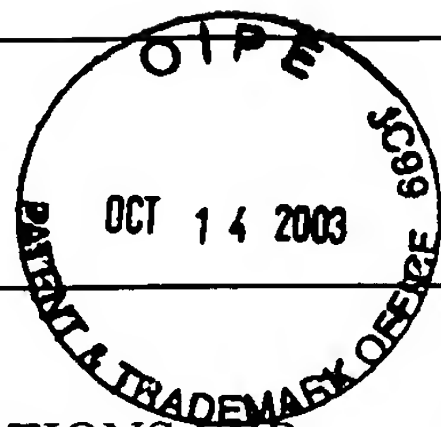
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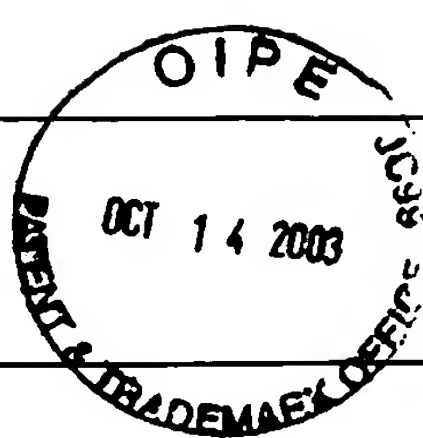
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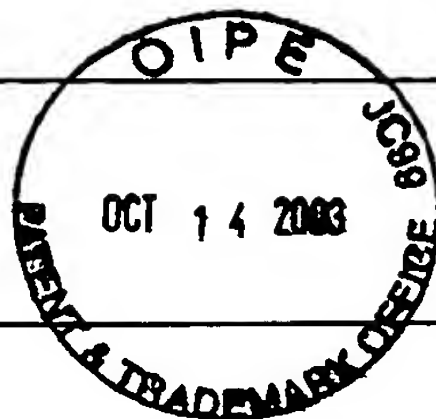
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